

Recording/Playback Amplifier for VHS VCRs

Overview

The LA70011 and LA70011M are recording/playback amplifiers for VHS VCR video signals. When used in combination with the LA71000M and LA71500M Series of video signal processing ICs, they permit Y/C recording without current adjustment.

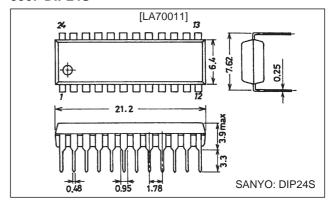
Features

- Connecting the playback amplifier input directly to the head reduces the number of external elements required.
- The recording amplifiers use a fixed-current drive configuration that yields stable recording characteristics even under changing loads. They include built-in automatic gain control circuits.
- Using the same dimensions and pin assignments as the LA70001 and LA70001M permits the use of the same circuit boards as these earlier chips. The LA70011 can also be mounted at the right end of an LA70020 socket.

Package Dimensions

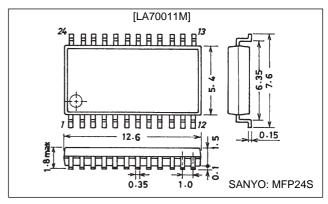
unit: mm

3067-DIP24S



unit: mm

3112-MFP24S



Specifications

Maximum Ratings at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Maximum power supply voltage	V _{CC} max		7.0	V
Maximum power discipation	Pd max	Ta ≤ 65°C [LA70011]	600	mW
Maximum power dissipation		Ta ≤ 65°C [LA70011M] 114.3 × 76.1 × 1.6 mm: glass epoxy	500	mW
Operating temperature	Topr		-10 to +65	°C
Storage temperature	Tstg		-40 to +150	°C

Operating Conditions at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Recommended power supply voltage	V _{CC}		5.0	V
Operating power supply voltage range	V _{CC} op		4.8 to 5.5	V

Operating Characteristics at $Ta = 25^{\circ}C$

Parameter		Symbol	Conditions	Ratings			Unit
		Cyrribor	Conditions	min	typ	max	Onic
Playback Mode							
Current drain		I _{CCP}	Current flowing into pin 13	44	53	60	mA
	SP-L CH1	G _{VP} 1		56	59	62	dB
Voltage gain	SP-H CH2	G _{VP} 2	V _{IN} = 38 mVp-p, f = 1 MHz	56	59	62	dB
0 0	EP-L CH3	G _{VP} 3	"'	56	59	62	dB
	EP-H CH4	G _{VP} 4		56	59	62	dB
Voltage gain difference		∆G _{VP} 1	G _{VP} 1 — G _{VP} 2	-1	0	+1	dB
		∆G _{VP} 2	G _{VP} 3 — G _{VP} 4	-1	0	+1	dB
Intermode gain difference		∆G _{VP} 3	G _{VP} 3 — G _{VP} 1	-1	0	+1	dB
Converted input noise voltage	CH1 CH2 CH3 CH4	V _{NIN1} V _{NIN2} V _{NIN3} V _{NIN4}	Ratio of the output from a 1.1 MHz low pass filter to the output with no input under the same conditions as those used for measuring voltage gain.		1.0	1.5	μVrm
CH1 CH2 Frequency characteristic CH3 CH4		ΔV_{fp} 1 ΔV_{fp2} ΔV_{fp3} ΔV_{fp4}	Ratios of the output for V_{IN} = 38 mVp-p and f = 7 MHz to the voltage gains $G_{VP}1$, $G_{VP}2$, $G_{VP}3$, and $G_{VP}4$.	-2.5	0		dB
Secondary harmonic distortion	CH1 CH2 CH3 CH4	$\Delta V_{HDP}1$ ΔV_{HDP2} ΔV_{HDP3} ΔV_{HDP4}	Ratio of the 8 MHz (secondary) component of the output to its 4 MHz (primary) component for V _{IN} = 38 mVp-p and f = 4 MHz.		-40	– 35	dB
Maximum output level	CH1 CH2 CH3 CH4	ΔV _{OMP} 1 ΔV _{OMP2} ΔV _{OMP3} ΔV _{OMP4}	Output level, for f = 1 MHz, at which the ratio of the 3 MHz (tertiary) component to the 1 MHz (primary) component is -30 dB.	1.0	1.2		Vp-p
Crosstalk SP		V _{CR} 1	Ratio of the output for $V_{IN} = 38 \text{ mVp-p}$ and $f = 4 \text{ MHz}$ to $G_{VP}1$.		-40	-35	dB
		V _{CR} 2	Ratio of the output for $V_{IN} = 38 \text{ mVp-p}$ and $f = 4 \text{ MHz}$ to $G_{VP}2$.		-40	-35	dB
		V _{CR} 3	Ratio of the output for V_{IN} = 38 mVp-p and f = 4 MHz to G_{VP} 3.		-40	-35	dB
Crosstalk EP		V _{CR} 4	Ratio of the output for $V_{IN} = 38 \text{ mVp-p}$ and $f = 4 \text{ MHz}$ to $G_{VP}4$.		-40	-35	dB
		ΔV _{ODC} 1	CH1 — CH2				
		ΔV _{ODC} 2	CH3 — CH4				
		ΔV _{ODC} 3	CH1 — CH3	400			
Output DC offset		ΔV _{ODC} 4	CH2 — CH4	-100	0	+100	mV
		ΔV _{ODC} 5	CH1 — CH4				
		ΔV _{ODC} 6	CH2 — CH3				
Envelope detector output pin vol	tage	V _{ENV}	T6 DC level with no signal input.	0.0	08	1.3	V
		V _{ENVSP} 1	T6 DC level at which T7A output level is 175 mVp-p for f = 4 MHz.	2.0	2.5	3.0	V
Envelope detector output pin vol	tage SP	V _{ENVSP} 2	T6 DC level at which T7A output level is 400 mVp-p for f = 4 MHz.	4.0	4.5	5.0	V
		V _{ENVEP} 1	T6 DC level at which T7A output level is 125 mVp-p for f = 4 MHz.	2.0	2.5	3.0	V
Envelope detector output pin vol	tage EP	V _{ENVEP} 2	T6 DC level at which T7A output level is 300 mVp-p for f = 4 MHz.	4.0	4.5	5.0	V
		V _{COMP} 1	T2 DC level for V_{IN} = 38 mVp-p and f = 4 MHz.		0.4	0.7	V
Comparator output voltage		V _{COMP} 2	T2 DC level for $V_{IN} = 38 \text{ mVp-p}$ and $f = 4 \text{ MHz}$.	4.5	4.8	· · · · · · · · · · · · · · · · · · ·	V
SW-Tr on resistance during play	back	R _{PON} 17 R _{PON} 22	DC difference for 1 and 2 mA current inputs.		4	6	Ω
		TR1-1	Normal → Trick1 : *1	3.2		5.0	V
		TR1-2	Trick1 → Normal	1.2		2.8	V
Trick threshold level		TR2-1	Normal → Trick2 : *1	0.0		0.8	V
		TR2-2	Trick2 → Normal	1.2		2.8	V

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Parameter	Cumbal	Conditions		Ratings		Unit
Parameter	Symbol	Conditions	min	typ	max	Unit
	HAP-1	SP → EP : *1	1.7		5.0	V
HA playback threshold level	HAP-2	EPSP	0.0		1.3	V
	SW30-1	Lch → Hch : *1	1.2		5.0	V
SW30 threshold level	SW30-2	Hch → Lch	0.0		0.8	V
Recording Mode						•
Current drain	I _{CCR}	Current input at pin 13.	52	59	66	mA
REC AGC AMP output level	V _{RSP}	Output level for $V_{IN} = 400 \text{ mVp-p}$ and $f = 4 \text{ MHz}$.	127	135	143	mVp-p
	V _{REP}		104	111	119	mVp-p
Intermode gain difference	∆GVR	VRSP/VREP	1.4	1.7	2.0	dB
	ΔV_{AGC} 1-SP ΔV_{AGC} 1-EP	Output level divided by V_{RSP} or V_{REP} for $f = 4$ MHz and $V_{IN} = 700$ mVp-p.		0.5	1.0	dB
REC AGC AMP control characteristic	ΔV_{AGC} 2-SP ΔV_{AGC} 2-EP	Output level divided by V_{RSP} or V_{REP} for $f = 4$ MHz and $V_{IN} = 100$ mVp-p.	-1.0	-0.5		dB
REC AGC AMP frequency characteristic	ΔV _{FRS} ΔV _{FRE}	Ratio of f = 7 MHz output to f = 1 MHz output for V_{IN} = 400 mVp-p. *2	-1	0	+1	dB
REC AGC AMP secondary primary distortion	ΔV_{HDRS} ΔV_{HDRE}	Ratio of the 8 MHz (secondary) component of the output to its 4 MHz (primary) component for V _{IN} = 400 mVp-p and f = 4 MHz.		-45	-40	dB
REC AGC AMP maximum output level	$\Delta V_{MOSP} \ \Delta V_{MOEP}$	Output level, for f = 4 MHz, at which the secondary distortion is –35 dB.	20	22		mApp
REC AGC AMP muting attenuation	$\Delta V_{MRS} \ \Delta V_{MRE}$	Output level divided by V_{RSP} or V_{REP} for $f = 4$ MHz and $V_{IN} = 400$ mVp-p.		-45	-40	dB
REC AGC AMP cross modulation relative level	ΔV _{CYS} ΔV _{CYE}	Output ratio (4M \pm 629k)/4M for V_{IN} = 400 mVp-p and f = 4 MHz at T9A and V_{IN} = 2.4 Vp-p and f = 629 kHz at T10A.		-45	-40	dB
HA REC threshold level	H _{AR} -1	SP → EP : *1	1.7		5.0	V
TIVITEO AIROSHOIG IOVOI	H _{AR} -2	$EP \to SP$	0.0		1.3	V
REC MUTE threshold level	MUTE-1	MUTE OFF → MUTE ON *1	1.2		2.8	V
NEO MOTE UIIOGNOID IOVOI	MUTE-2	$MUTE\;ON\toMUTE\;OFF$	3.2		5.0	V
REC PB threshold level	PB-REC	PB → REC *1	1.2		5.0	V
NEO I D'allesticia level	REC-PB	$REC \to PB$	0.0		0.8	V

Notes:* Before measuring the items under Playback Mode, input a 0 to 5.0 V trigger pulse to T5 (H-SYNC), the pin from which the LA70011 takes its T3 (HA) control switch timing.

* The resistance between pins 13 and 14 must be accurate to within 1.0%.

*1. These are voltage application points.

*2. Apply a DC voltage of approximately 1.8 V to the AGC wave detector filter pin (pin 15) to fix the AGC amplifier gain.

*3. Apply a DC voltage to the REC-CUR-Adj pin (pin 12) and adjust the output level.

Pin Descriptions

Pin Number	Pin Name	Stand	lard DC Voltage (V)	Equivalent Circuit	Notes
1	TRICK-H			VCC 120k Ω Trick1 Sok Ω Trick2 Comp Trick2 Trick2 A09418	Trick1 3.0 V NORMAL 1.0 V Trick2
2	COMP-OUT	PB REC	H: min. 4.5 V L: max. 0.7 V Open	100Ω 100Ω 1kΩ 1kΩ A09419	EP > SP ENV High
3	HA (EP/SP)			100kΩ HA Comp 1.5V 1.5V 1.5V A09420	EP 1.0 V
4	SW30			1kΩ SW30 Comp 1V 7777 A09421	Hch Lch
5	H-SYNC			5 20kΩ H SYNC Comp 1.5V 777 A09422	SYNC H 1.5 V

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Pin Number	Pin Name	Stan	dard DC Voltage (V)	Equivalent Circuit	Notes
6	ENVDET-OUT	РВ	See relevant documents.	ΛVcc 100Ω	
		REC	0	6 + 20kΩ × 777 A09423	
7	PB-OUT	РВ	1.7	√VCC 100Ω∰	
7 P	15-001	REC	2.1	7 ↓ 1 mA A09424	
8 20	GND				
9	REC-Y-IN	РВ	4.0	300Ω 5kΩ 	
		REC 3.7			
10	REC-C-IN	РВ	4.0	25kΩ 300Ω 5kΩ ——————————————————————————————————	
.0		REC	3.7		
11	REC/MUTE/PB			20kΩ PB/REC Omp 0.8V 80kΩ 7777 A09427	REC 3.0 V REC MUTE 1.0 V

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Pin Number	Pin Name	Stan	dard DC Voltage (V)	Equivalent Circuit	Notes	
R	REC-CURRENT- ADJ2	РВ	2.5 V 100kΩ 300Ω	l 5 l		
12		REC	2.5 V	100kΩ 7777 A09428		
13	Vcc					
14	REC-CURRENT-	РВ	5.0	3000		
14	ADJ1	REC	4.5	1kΩ,1.3kΩ A09429		
15	REC-AGC-FILT	РВ	0	300Ω 20kΩ The state of the sta		
	RECAGO TIET		REC	1.6	10kΩ \$\begin{array}{c} \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\	
16 19		2.1	REC-ON VCC			
		REC	4.1	②24 PB-ON 2.4mA		
17 22	REC SP OUT EP OUT	PB 2.1 REC SP OUT	2.1	10kΩ		
		REC	4.1	PB-ON \$ 16.7Ω 		

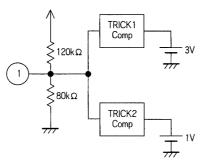
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Pin Number	Pin Name	Stan	dard DC Voltage (V)	Equivalent Circuit	Notes
18	PB FILT	РВ	0	18€3 ↑ <u>\$</u> 20kΩ	
23	181121	REC	2.5	PB-ON \$20kΩ A09433	

Usage Notes

Control Pin Logic

Switching Trick Mode with Pin 1



GND < pin 1 level - DC < 1.0 V: TRICK2 1.0 V < pin 1 level - DC < 3.0 V: NORMAL 3.0 V < pin 1 level - DC < 5.0 V: TRICK1

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NORMAL Mode

Two channels selected with pin 3 (EP/SP): ON

Envelope comparator: OFF

TRICK1 and TRICK2 Modes

All four channels: ON Envelope comparator: OFF

Difference between TRICK1 and TRICK2 modes (See the Block Diagram.)

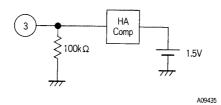
TRICK1 is a special playback mode using the following path

$$\boxed{\text{Envelope comparator OUT (pin 2)}} \rightarrow \boxed{\text{Servo (microcontroller)}} \rightarrow \boxed{\text{Pin 3 (HA)}} \rightarrow \boxed{\text{HA-SW}}$$

TRICK2 provides SP searching

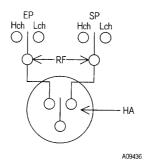
$$\boxed{ \text{Envelope comparator OUT} \rightarrow \boxed{ \text{HA-SW} } }$$

HA-SW (EP/SP mode switch): Pin 3



GND < pin 3 level - DC < 1.5 V: SP mode 1.5 V < pin 3 level - DC < 5 V: EP mode Synchronization of HA Switching Timing during Playback with H-SYNC Signal

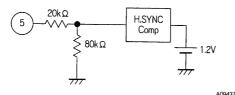
During playback, the LA70011's video circuits synchronize the HA-SW switching timing shown in the following figure with the H-SYNC signal from pin 5. (Other EP/SP switching takes place in real time.)



Comparator Output: Pin 2

EP envelope > SP envelope: High (min. 4.0 V) EP envelope < SP envelope: Low (max. 0.7 V)

H-SYNC Input: Pin 5



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Pin 5 level - DC > 1.5 V: H-SYNC interval

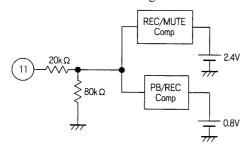
Playback:

- Determines timing of HA switching (EP/SP)
- Determines timing of special playback

Recording:

- Serves as gate pulse for REC-AGC-AMP SYNC unit

REC/REC-MUTE/PB Switching: Pin 11

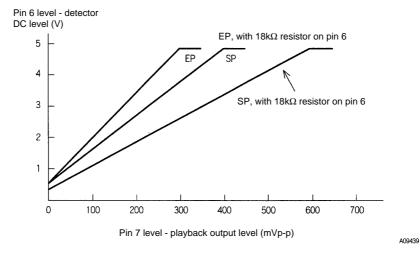


GND < pin 11 level - DC < 1.0 V: PB mode 1.0 V < pin 11 level - DC < 3.0 V: REC mode, REC-MUTE 3.0 V < pin 11 level - DC < 5.0 V: REC mode

Envelope Detector Characteristic: Pin 6

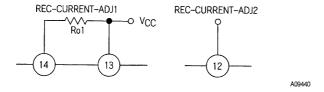
The LA70011 includes a built-in playback signal envelope detector circuit for use in automating tracking adjustment.

Envelope detector voltage characteristic



REC AMP Gain Control

The LA70011 eliminates recording current adjustment by adding an automatic gain control circuit to the recording amplifier. It is also possible to change the recording current with the following methods.



REC-CURRENT-ADJ2 Open

The internal bias forces the DC level at pin 12 to $1/2~V_{CC}$ (that is, approximately 2.5 V), and $R_{O}1$ determines the recording current.

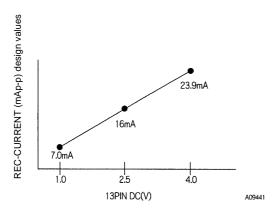
Design values

 $R_O 1 = 1.5 \text{ k}\Omega = 16.0 \text{ mA (SP) (per channel)}$

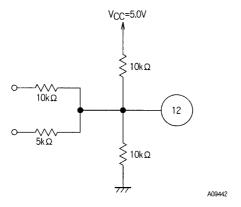
 $R_{\Omega}1 = 1.5 \text{ k}\Omega = 12.7 \text{ mA (EP)}$

REC-CURRENT-ADJ2 Used

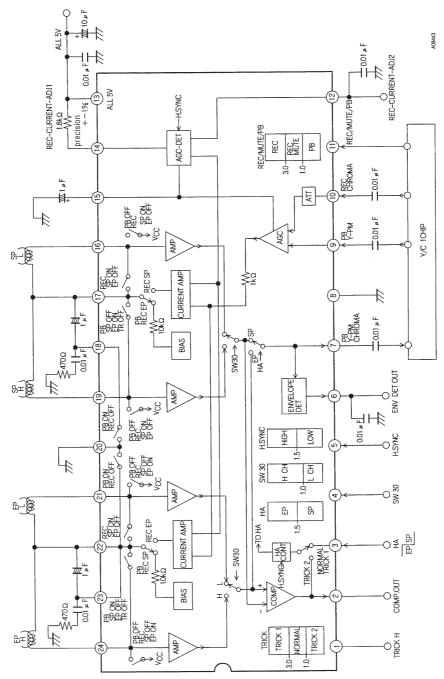
Applying a DC control voltage between 1 and 4 V to pin 12 adjusts the figure determined by $R_{O}1$ between -6.0 dB and +3.5 dB.



Note: One possible circuit for applying this voltage is the following, which provides 9 modes between 1 and 4 V.



Block Diagram



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